## NSN 5961-00-194-8779

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**Fiig:** A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-194-8779 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Field effect **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -10.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and -10.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source **Current Rating Per Characteristic:** 1.00 milliamperes drain current **Power Rating Per Characteristic:** 100.0 milliwatts collector power dissipation **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pn **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No